

REF34-Q1 Low-Drift, Low-Power, Small-Footprint Series Voltage References

1 Features

- AEC-Q100 Qualified With the Following Results:
 - Device Temperature Grade 1: -40°C to $+125^{\circ}\text{C}$ Ambient Operating Temperature
 - Device HBM ESD Classification Level 2
 - Device CDM ESD Classification Level C6
- Initial Accuracy: $\pm 0.05\%$ (Maximum)
- Temperature Coefficient : 6 ppm/ $^{\circ}\text{C}$ (Maximum)
- Operating Temperature Range: -40°C to $+125^{\circ}\text{C}$
- Output Voltage Options: 2.5V, 3.0V, 3.3V, 4.096V, 5.0V
- Output Current: $\pm 10\text{ mA}$
- Low Quiescent Current: 95 μA (maximum)
- Low Shutdown Mode Current: 3 μA (maximum)
- Wide Input Voltage: 12 V
- Output 1/f Noise (0.1 Hz to 10 Hz): 3.8 $\mu\text{V}_{\text{PP}}/\text{V}$
- Excellent Long-Term Stability 25 ppm/1000 hrs
- Small Footprint 6-Pin SOT-23 Package

2 Applications

- Body Control Modules
- On Board Chargers
- Traction Inverters
- Battery Management Systems
- Advanced Driver Assistance Systems

3 Description

The REF34-Q1 devices are low-temperature-drift (6 ppm/ $^{\circ}\text{C}$), low-power, high-precision CMOS voltage references. The devices have $\pm 0.05\%$ initial accuracy and low operating current with power consumption less than 95 μA . These devices also offer very low output noise of 3.8 $\mu\text{V}_{\text{PP}}/\text{V}$, which enable the devices to maintain high signal integrity with high-resolution data converters and noise critical systems.

Stability and system reliability are further improved by the low output-voltage hysteresis of these devices and low long-term output voltage drift. Furthermore, the small size and low operating current of the devices (95 μA) make them an excellent choice for battery-powered applications. The REF34-Q1 features an enable pin that can set the device into shutdown where it consumes a low stand by current (3 μA) to help with overall system power during standby.

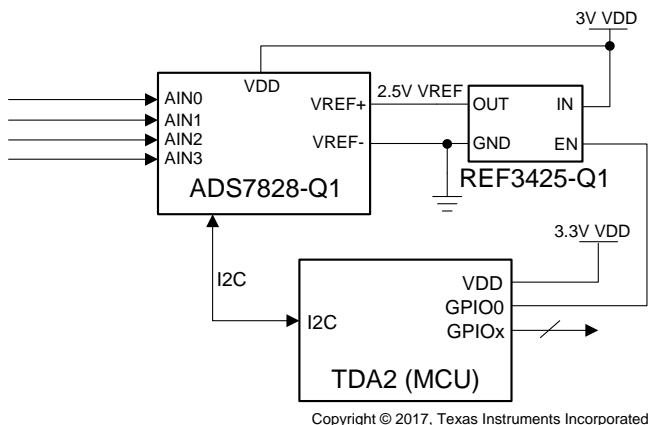
The REF34-Q1 family is specified for the wide temperature range of -40°C to $+125^{\circ}\text{C}$. Contact the TI sales representative for additional voltage options.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
REF3425-Q1	SOT-23 (6)	2.90 mm x 1.60 mm
REF3430-Q1	SOT-23 (6)	2.90 mm x 1.60 mm
REF3433-Q1	SOT-23 (6)	2.90 mm x 1.60 mm
REF3440-Q1	SOT-23 (6)	2.90 mm x 1.60 mm
REF3450-Q1	SOT-23 (6)	2.90 mm x 1.60 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic



Dropout vs Current Load Over Temperature

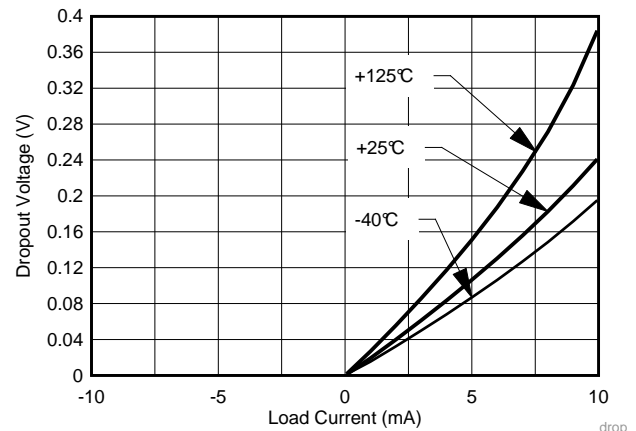


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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES
September 2018	*	Initial release

Changes from Original (July 2018) to Revision A

Page

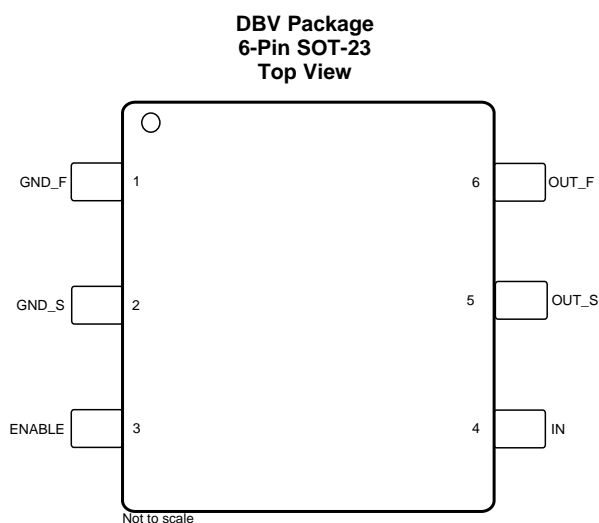
• Changed Advance Information to Production Data	1
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5 Device Comparison Table

PRODUCT ⁽¹⁾	V _{OUT}
REF3425-Q1	2.5 V
REF3430-Q1	3.0 V
REF3433-Q1	3.3 V
REF3440-Q1	4.096 V
REF3450-Q1	5.0 V

(1) For full orderable part number please refer to Section 14.

6 Pin Configuration and Functions



Pin Functions

PIN		TYPE	DESCRIPTION
NO.	NAME		
1	GND_F	Ground	Ground force connection
2	GND_S	Ground	Ground sense connection
3	ENABLE	Input	Enable connection. Enables or disables the device.
4	IN	Power	Input supply voltage connection
5	OUT_S	Output	Reference voltage output sense connection
6	OUT_F	Output	Reference voltage output force connection

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Input voltage	IN	$V_{REF} + 0.05$	13	V
	EN	−0.3	IN + 0.3	
Output voltage	V_{REF}	−0.3	5.5	V
Output short circuit current			20	mA
Temperature	Operating, T_A	−55	150	°C
	Storage T_{stg}	−65	170	

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$ Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	±2500	V
	Charged-device model (CDM), per AEC Q100-011	±1500	

- (1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
IN	Supply input voltage ($I_L = 0$ mA, $T_A = 25^\circ\text{C}$)	$V_{REF} + V_{DO}$ ⁽¹⁾		12	V
EN	Enable voltage	0		IN	V
I_L	Output current	−10		10	mA
T_A	Operating temperature	−40	25	125	°C

- (1) Dropout voltage

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		REF34-Q1	UNIT
		DBV (SOT-23)	
		6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	122.6	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	80.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	42	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	23.2	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	41.9	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

7.5 Electrical Characteristics

At $T_A = 25^\circ\text{C}$ unless otherwise noted.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
ACCURACY AND DRIFT							
	Output voltage accuracy	T _A = 25°C		-0.05 %	0.05%		
	Output voltage temperature coefficient ⁽¹⁾	-40°C ≤ T _A ≤ 125°C			2.5	6	ppm/°C
LINE AND LOAD REGULATION							
ΔV _(OΔVIN)	Line regulation	V _{IN} = 2.55 V to 12 V , T _A = 25°C		2		ppm/V	
		V _{IN} = V _{REF} + V _{DO} ⁽²⁾ to 12 V, -40°C ≤ T _A ≤ 125°C		15			
ΔV _(OΔIL)	Load regulation	I _L = 0 mA to 10 mA, V _{IN} = 3 V, T _A = 25°C	Sourcing		20		ppm/mA
		I _L = 0 mA to 10 mA, V _{IN} = 3 V, -40°C ≤ T _A ≤ 125°C	Sourcing		30		
		I _L = 0 mA to -10 mA, V _{IN} = V _{REF} + V _{DO} ⁽³⁾ , T _A = 25°C	Sinking	REF3425-Q1	40		
				REF3430-Q1	43		
				REF3433-Q1	48		
				REF3440-Q1	60		
				REF3450-Q1	70		
		I _L = 0 mA to -10 mA, V _{IN} = V _{REF} + V _{DO} ⁽³⁾ , -40°C ≤ T _A ≤ 125°C	Sinking	REF3425-Q1	70		
				REF3430-Q1	75		
				REF3433-Q1	84		
REF3440-Q1	98						
REF3450-Q1	140						
I _{sc}	Short-circuit current (Output shorted to ground)	V _{REF} = 0, T _A = 25°C			18	22	mA
NOISE							
e _n p-p	Output voltage noise ⁽⁴⁾	f = 0.1 Hz to 10 Hz		5		μV p-p/V	
		f = 0.1 Hz to 10 Hz (REF3440-Q1 and REF3450-Q1)		3.8		μV p-p/V	
		f = 10 Hz to 10 kHz		24		μV rms	
e _n	Output voltage noise density	f = 1 kHz		0.25		ppm/√Hz	
		f = 1 kHz (REF3440-Q1 and REF3450-Q1)		0.2		ppm/√Hz	
HYSTERESIS AND LONG TERM STABILITY							
	Long-term stability ⁽⁵⁾	0 - 1000 hours at 35°C		25		ppm	
		1000 - 2000 hours at 35°C		10			
	Output voltage hysteresis ⁽⁶⁾	T _A = 25°C to -40°C to 125°C to 25°C, Cycle 1		30		ppm	
		T _A = 25°C to -40°C to 125°C to 25°C, Cycle 2		10			

- (1) Temperature drift is specified according to the box method. See [Feature Description](#) for more details.
- (2) The dropout voltage in line regulation test condition is 50 mV.
- (3) The dropout voltage in test condition is 500 mV.
- (4) The peak-to-peak noise measurement procedure is explained in more detail in [Noise Performance](#).
- (5) Long-term stability measurement procedure is explained in more in detail in [Long-Term Stability](#).
- (6) The thermal hysteresis measurement procedure is explained in more detail in [Thermal Hysteresis](#).

REF34-Q1

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Electrical Characteristics (continued)

At $T_A = 25^\circ\text{C}$ unless otherwise noted.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
TURNON							
t _{ON}	Turn on time	0.1% of output voltage settling, C _L = 10 μF				2.5	ms
CAPACITIVE LOAD							
C _L	Stable output capacitor value	−40°C ≤ T _A ≤ 125°C		0.1		10	μF
OUTPUT VOLTAGE							
V _{REF}	Output voltage	REF3425Q1		2.5			V
		REF3430Q1		3			V
		REF3433Q1		3.3			V
		REF3440Q1		4.096			V
		REF3450Q1		5.0			V
POWER SUPPLY							
V _{IN}	Input voltage			V _{REF} + V _{DO}		12	V
I _L	Output current capacity	V _{IN} = V _{REF} + V _{DO} ⁽³⁾ to 12 V	Sourcing	10			mA
		V _{IN} = V _{REF} + V _{DO} ⁽³⁾ to 12 V	Sinking	−10			
I _Q	Quiescent current	−40°C ≤ T _A ≤ 125°C	Active mode	72	95		μA
		−40°C ≤ T _A ≤ 125°C	Shutdown mode	2.5	3		
V _{DO}	Dropout voltage	I _L = 0 mA, T _A = 25°C		50			mV
		I _L = 0 mA, −40°C ≤ T _A ≤ +125°C		100			
		I _L = 10 mA, −40°C ≤ T _A ≤ +125°C		500			
V _{EN}	ENABLE pin voltage	Voltage reference in active mode (EN = 1)		1.6			V
		Voltage reference in shutdown mode (EN = 0)		0.5			
I _{EN}	ENABLE pin leakage current	V _{EN} = V _{IN} =12 V, −40°C ≤ T _A ≤ 125°C		1	2		μA

7.6 Typical Characteristics

at $T_A = 25^\circ\text{C}$, $V_{IN} = V_{EN} = 12\text{ V}$, $I_L = 0\text{ mA}$, $C_L = 10\text{ }\mu\text{F}$, $C_{IN} = 0.1\text{ }\mu\text{F}$ (unless otherwise noted)

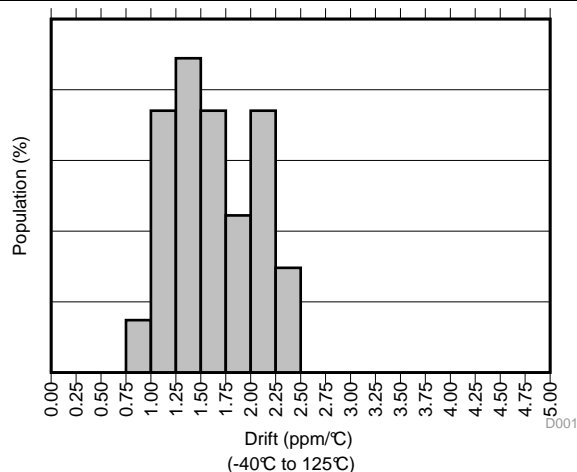


Figure 1. Temperature Drift

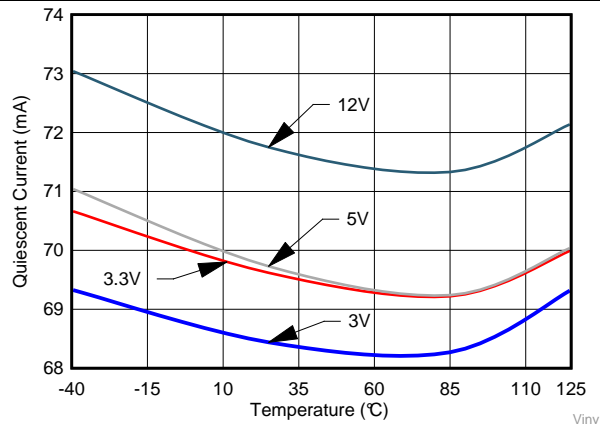


Figure 2. V_{IN} vs I_Q Over Temperature

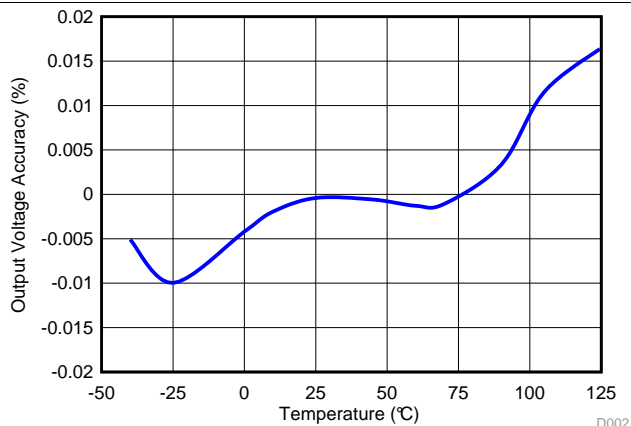


Figure 3. Output Voltage Accuracy vs Temperature

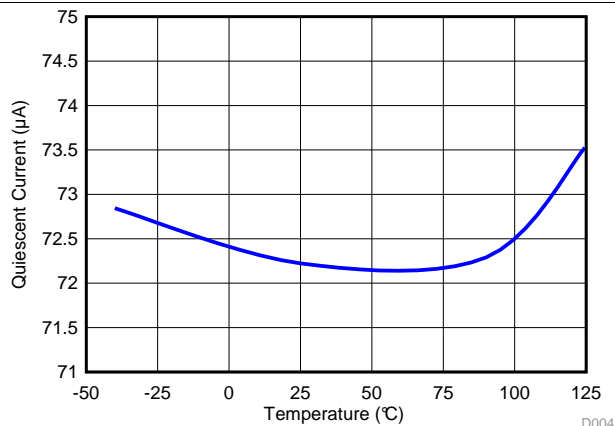


Figure 4. Quiescent Current vs Temperature

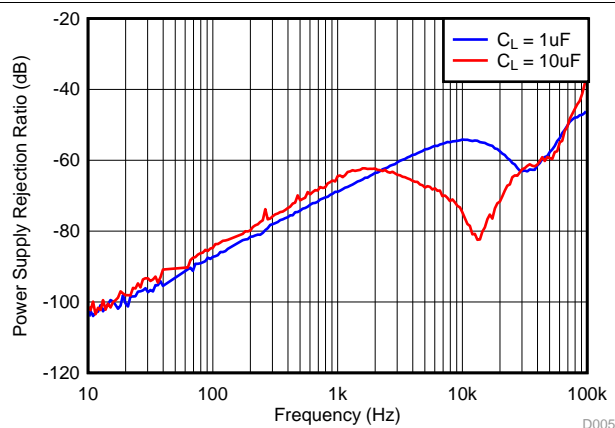


Figure 5. Power-Supply Rejection Ratio vs Frequency

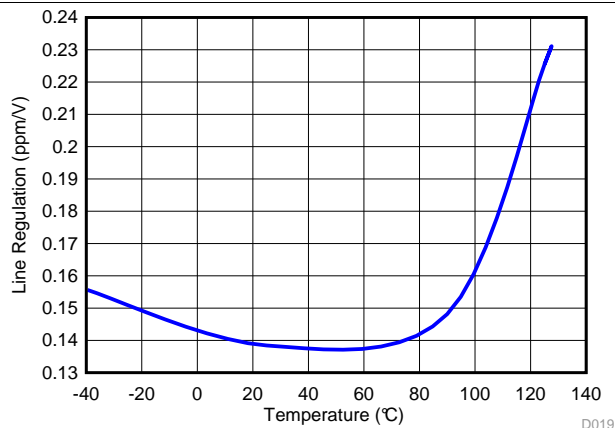


Figure 6. Line Regulation

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_{IN} = V_{EN} = 12\text{ V}$, $I_L = 0\text{ mA}$, $C_L = 10\text{ }\mu\text{F}$, $C_{IN} = 0.1\text{ }\mu\text{F}$ (unless otherwise noted)

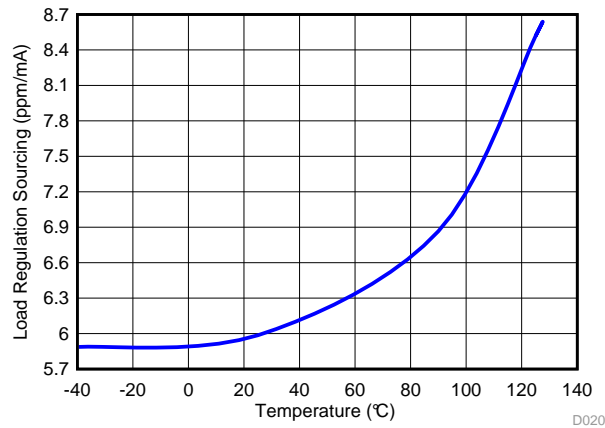


Figure 7. Load Regulation Sourcing

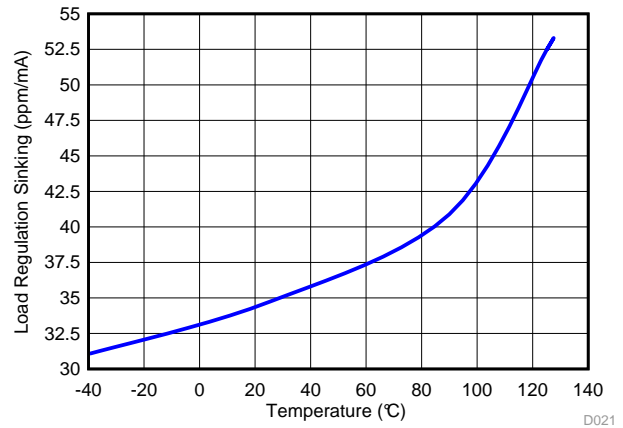


Figure 8. Load Regulation Sinking

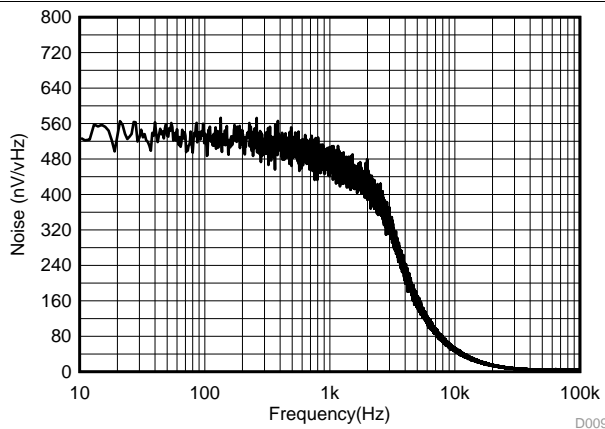


Figure 9. Noise Performance 10 Hz to 10 kHz

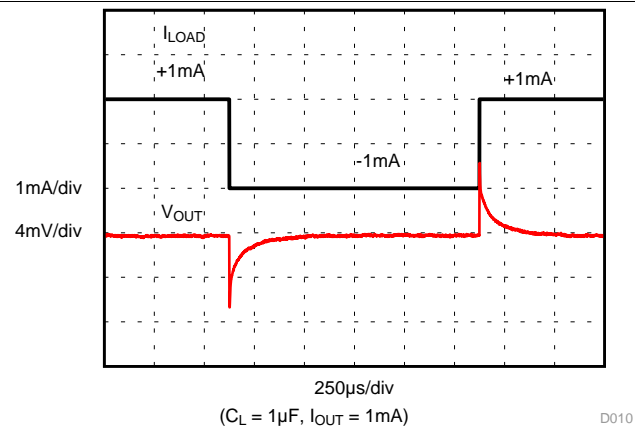


Figure 10. Load Transient

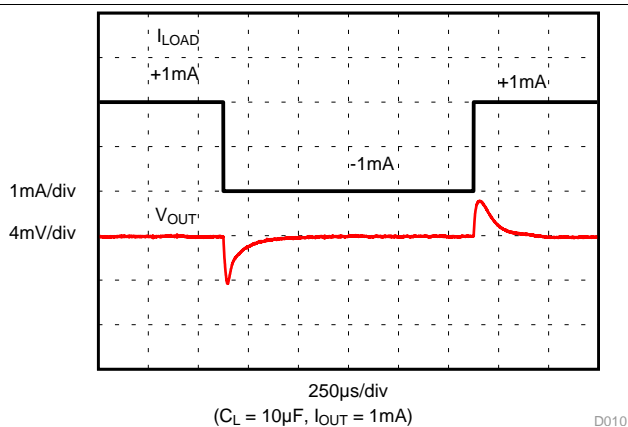


Figure 11. Load Transient

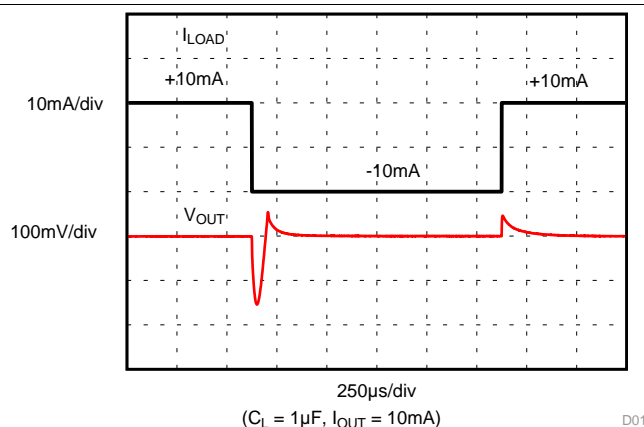


Figure 12. Load Transient

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_{IN} = V_{EN} = 12\text{ V}$, $I_L = 0\text{ mA}$, $C_L = 10\text{ }\mu\text{F}$, $C_{IN} = 0.1\text{ }\mu\text{F}$ (unless otherwise noted)

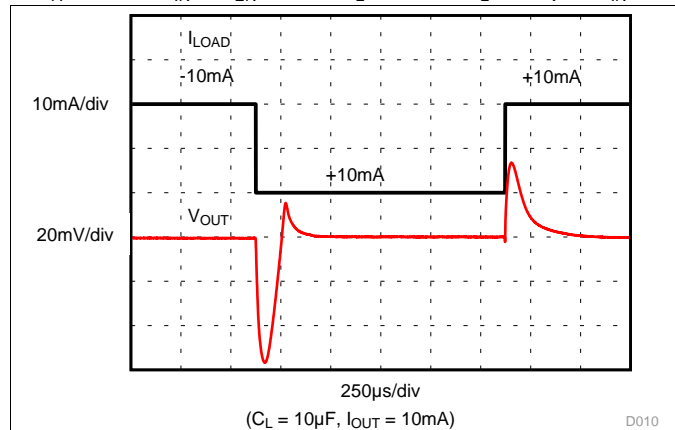


Figure 13. Load Transient

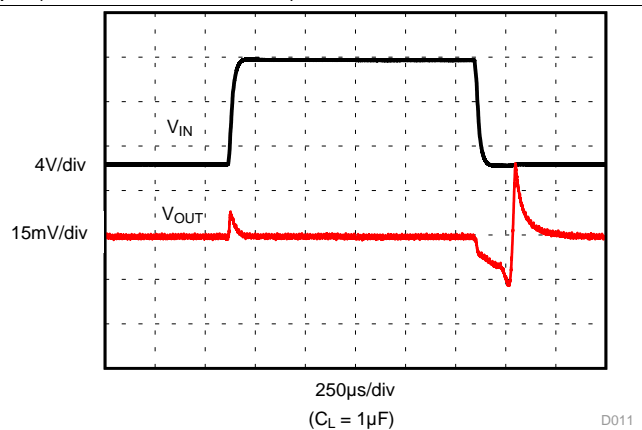


Figure 14. Line Transient

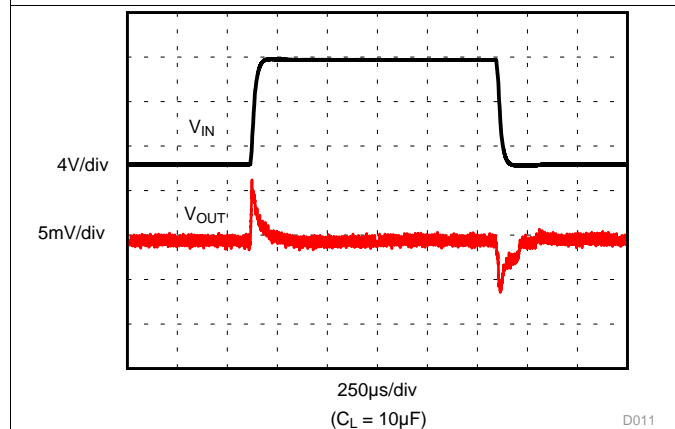


Figure 15. Line Transient

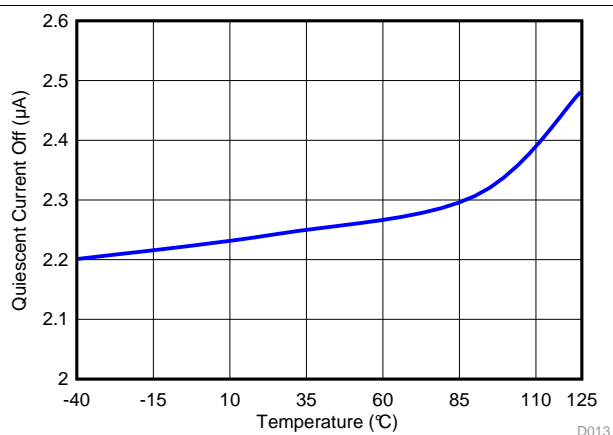


Figure 16. Quiescent Current Shutdown Mode

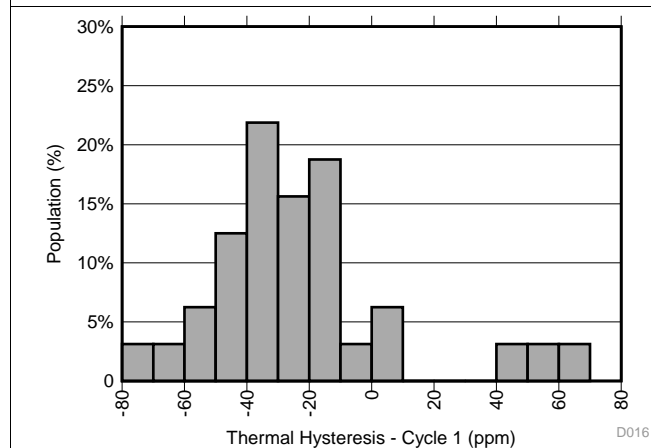


Figure 17. Thermal Hysteresis Distribution (Cycle 1)

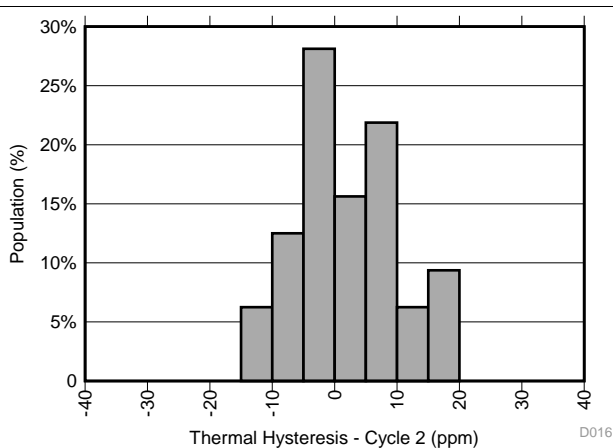
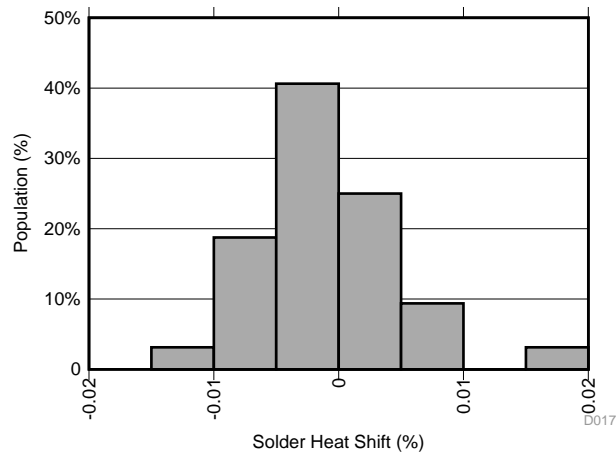


Figure 18. Thermal Hysteresis Distribution (Cycle 2)

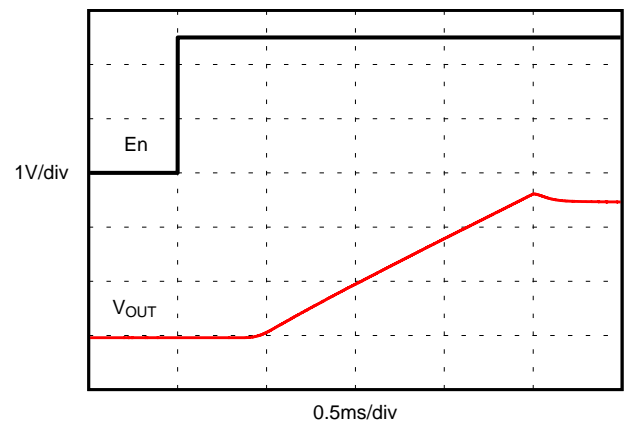
Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_{IN} = V_{EN} = 12\text{ V}$, $I_L = 0\text{ mA}$, $C_L = 10\text{ }\mu\text{F}$, $C_{IN} = 0.1\text{ }\mu\text{F}$ (unless otherwise noted)



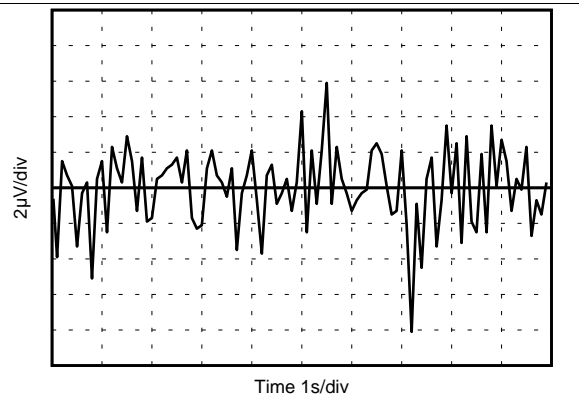
Refer to [Solder Heat Shift](#) for more information

Figure 19. Solder Heat Shift Distribution



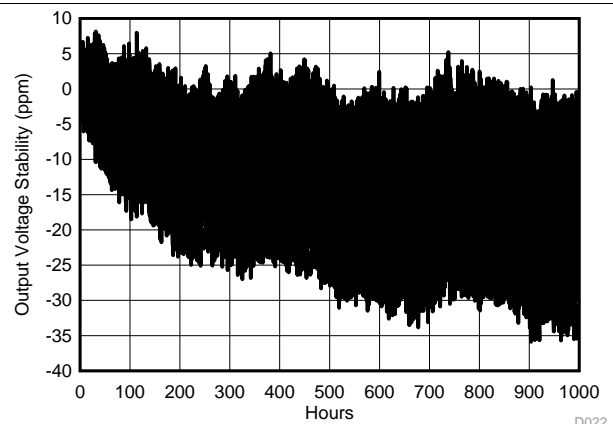
D018

Figure 20. Turnon Time (Enable)



D08_

Figure 21. 0.1-Hz to 10-Hz Noise (V_{REF})



D022

Figure 22. Long Term Stability - 1000 hours (V_{REF})

8 Parameter Measurement Information

8.1 Solder Heat Shift

The materials used in the manufacture of the REF34-Q1 have differing coefficients of thermal expansion, resulting in stress on the device die when the part is heated. Mechanical and thermal stress on the device die can cause the output voltages to shift, degrading the initial accuracy specifications of the product. Reflow soldering is a common cause of this error.

In order to illustrate this effect, a total of 32 devices were soldered on four printed circuit boards [16 devices on each printed circuit board (PCB)] using lead-free solder paste and the paste manufacturer suggested reflow profile. The reflow profile is as shown in [Figure 23](#). The printed circuit board is comprised of FR4 material. The board thickness is 1.65 mm and the area is 114 mm × 152 mm. All measurements were taken after baking in 150°C.

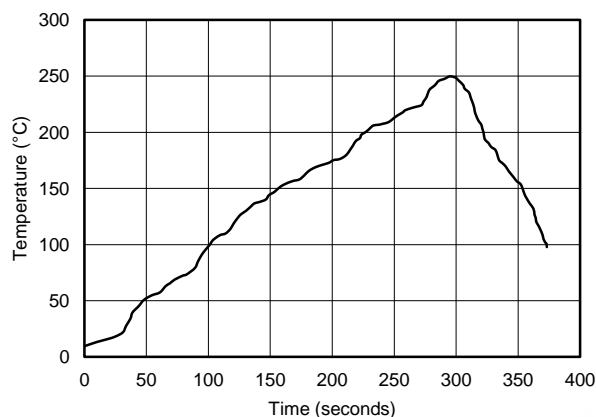


Figure 23. Reflow Profile

The reference output voltage is measured before and after the reflow process; the typical shift is displayed in [Figure 24](#). Although all tested units exhibit very low shifts (< 0.01%), higher shifts are also possible depending on the size, thickness, and material of the printed circuit board. An important note is that the histograms display the typical shift for exposure to a single reflow profile. Exposure to multiple reflows, as is common on PCBs with surface-mount components on both sides, causes additional shifts in the output bias voltage. If the PCB is exposed to multiple reflows, the device must be soldered in the second pass to minimize its exposure to thermal stress.

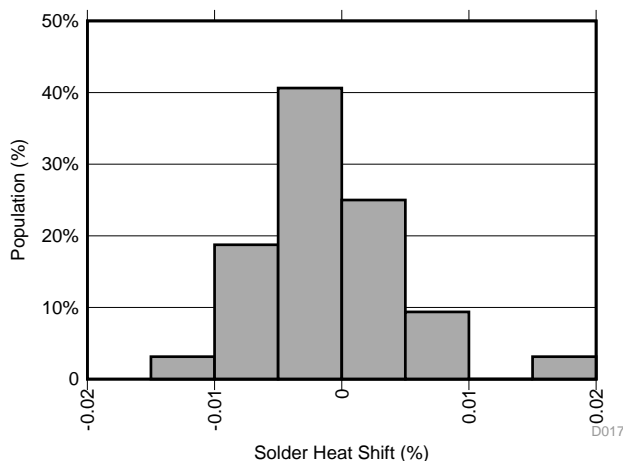


Figure 24. Solder Heat Shift Distribution, V_{REF} (%)

8.2 Long-Term Stability

One of the key parameters of the REF34-Q1 references is long-term stability. Typical characteristic expressed as: curves shows the typical drift value for the REF34-Q1 is 25 ppm from 0 to 1000 hours. This parameter is characterized by measuring 32 units at regular intervals for a period of 1000 hours. It is important to understand that long-term stability is not ensured by design and that the output from the device may shift beyond the typical 25 ppm specification at any time. For systems that require highly stable output voltages over long periods of time, the designer should consider burning in the devices prior to use to minimize the amount of output drift exhibited by the reference over time

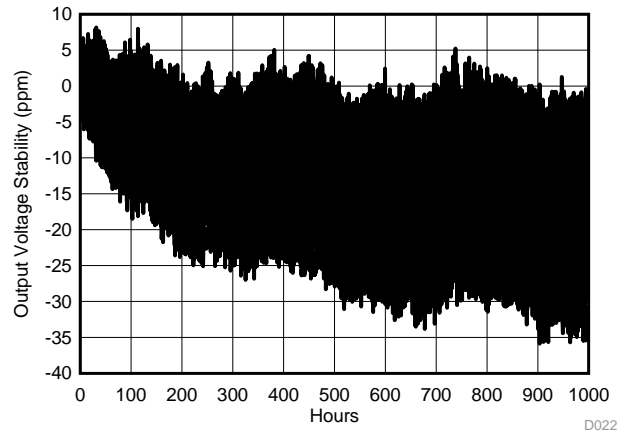


Figure 25. Long Term Stability - 1000 hours (V_{REF})

8.3 Thermal Hysteresis

Thermal hysteresis is measured with the REF34-Q1 soldered to a PCB, similar to a real-world application. Thermal hysteresis for the device is defined as the change in output voltage after operating the device at 25°C, cycling the device through the specified temperature range, and returning to 25°C. Hysteresis can be expressed by Equation 1:

$$V_{HYST} = \left(\frac{|V_{PRE} - V_{POST}|}{V_{NOM}} \right) \times 10^6 \text{ (ppm)}$$

where

- V_{HYST} = thermal hysteresis (in units of ppm)
- V_{NOM} = the specified output voltage
- V_{PRE} = output voltage measured at 25°C pre-temperature cycling
- V_{POST} = output voltage measured after the device has cycled from 25°C through the specified temperature range of –40°C to +125°C and returns to 25°C.

(1)

Thermal Hysteresis (continued)

Typical thermal hysteresis distribution is as shown in [Figure 26](#).

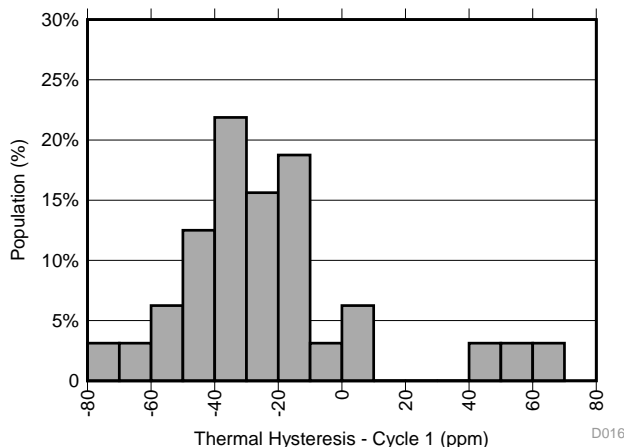


Figure 26. Thermal Hysteresis Distribution (V_{REF})

8.4 Power Dissipation

The REF34-Q1 voltage references are capable of source and sink up to 10 mA of load current across the rated input voltage range. However, when used in applications subject to high ambient temperatures, the input voltage and load current must be carefully monitored to ensure that the device does not exceed its maximum power dissipation rating. The maximum power dissipation of the device can be calculated with [Equation 2](#):

$$T_J = T_A + P_D \times R_{\theta JA}$$

where

- P_D is the device power dissipation
 - T_J is the device junction temperature
 - T_A is the ambient temperature
 - $R_{\theta JA}$ is the package (junction-to-air) thermal resistance
- (2)

Because of this relationship, acceptable load current in high temperature conditions may be less than the maximum current-sourcing capability of the device. In no case should the device be operated outside of its maximum power rating because doing so can result in premature failure or permanent damage to the device.

8.5 Noise Performance

Typical 0.1-Hz to 10-Hz voltage noise can be seen in [Figure 27](#) . Device noise increases with output voltage and operating temperature. Additional filtering can be used to improve output noise levels, although care must be taken to ensure the output impedance does not degrade ac performance. Peak-to-peak noise measurement setup is shown in [Figure 27](#).

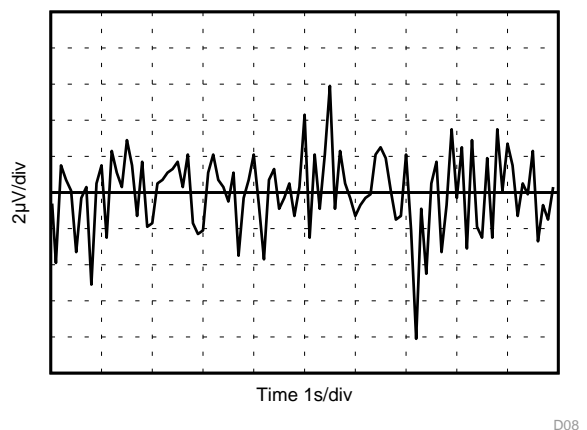


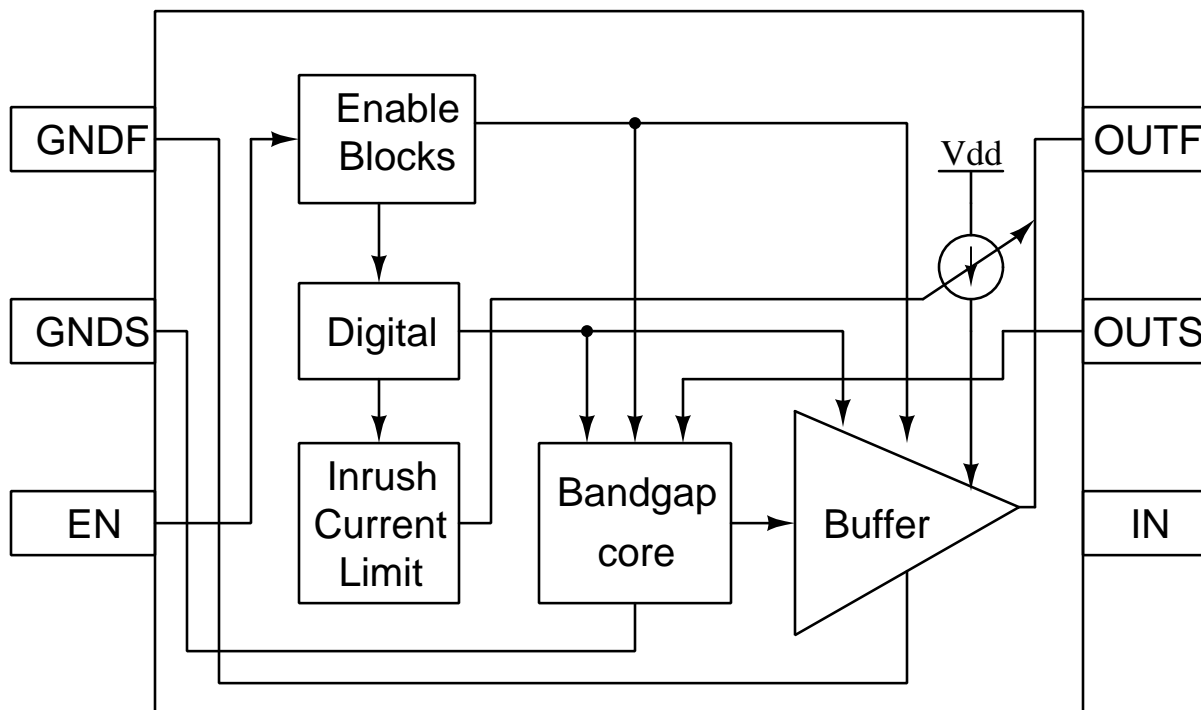
Figure 27. 0.1-Hz to 10-Hz Noise (V_{REF})

9 Detailed Description

9.1 Overview

The REF34-Q1 devices are a family of low-noise, precision bandgap voltage references that are specifically designed for excellent initial voltage accuracy and drift. The [Functional Block Diagram](#) is a simplified block diagram of the REF34-Q1 showing basic band-gap topology.

9.2 Functional Block Diagram



9.3 Feature Description

9.3.1 Supply Voltage

The REF34-Q1 family of references features an extremely low dropout voltage. For loaded conditions, a typical dropout voltage versus load is shown on the front page. The REF34-Q1 family features a low quiescent current that is extremely stable over changes in both temperature and supply. The typical room temperature quiescent current is 72 μA , and the maximum quiescent current over temperature is just 95 μA . Supply voltages below the specified levels can cause the REF34-Q1 to momentarily draw currents greater than the typical quiescent current. Use a power supply with a fast rising edge and low output impedance to easily prevent this issue.

9.3.2 Low Temperature Drift

The REF34-Q1 devices are designed for minimal drift error, which is defined as the change in output voltage over temperature. The drift is calculated using the box method, as described by [Equation 3](#):

$$\text{Drift} = \left(\frac{V_{\text{REF(MAX)}} - V_{\text{REF(MIN)}}}{V_{\text{REF}} \times \text{Temperature Range}} \right) \times 10^6 \quad (3)$$

Feature Description (continued)

9.3.3 Load Current

The REF34-Q1 family is specified to deliver a current load of ± 10 mA per output. The V_{REF} output of the device are protected from short circuits by limiting the output short-circuit current to 18 mA. The device temperature increases according to [Equation 4](#):

$$T_J = T_A + P_D \times R_{\theta JA}$$

where

- T_J = junction temperature ($^{\circ}\text{C}$),
 - T_A = ambient temperature ($^{\circ}\text{C}$),
 - P_D = power dissipated (W), and
 - $R_{\theta JA}$ = junction-to-ambient thermal resistance ($^{\circ}\text{C}/\text{W}$)
- (4)

The REF34-Q1 maximum junction temperature must not exceed the absolute maximum rating of 150°C .

9.4 Device Functional Modes

9.4.1 EN Pin

When the EN pin of the REF34-Q1 is pulled high, the device is in active mode. The device must be in active mode for normal operation. The REF34-Q1 can be placed in a low-power mode by pulling the ENABLE pin low. When in shutdown mode, the output of the device becomes high impedance and the quiescent current of the device reduces to $2\text{ }\mu\text{A}$ in shutdown mode. The EN pin must not be pulled higher than V_{IN} supply voltage. See the [Thermal Information](#) for logic high and logic low voltage levels.

10 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

As the REF34-Q1 devices have many applications and setups, there are many situations that this data sheet can not characterize in detail. Basic applications includes positive/negative voltage reference and data acquisition systems.

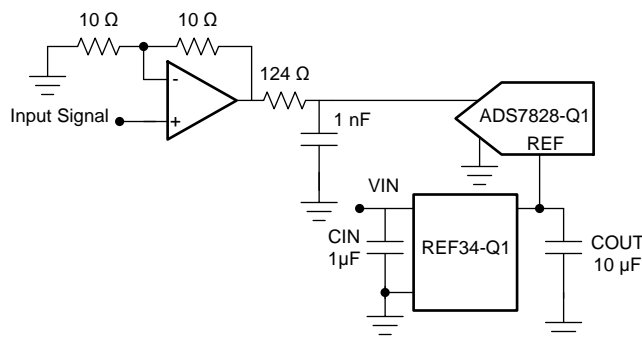
Table 1. Typical Applications and Companion ADC/DAC

APPLICATIONS	ADC/DAC/Controller
ADAS	ADS7828-Q1
HEV/EV	ADS7951-Q1, ADS1120-Q1, ADS1258, BQ76PL455A-Q1

10.2 Typical Applications

10.2.1 Basic Voltage Reference Connection

The circuit shown in [Figure 28](#) shows the basic configuration for the REF34-Q1 references. Connect bypass capacitors according to the guidelines in [Input and Output Capacitors](#).



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Figure 28. Basic Reference Connection

Typical Applications (continued)

10.2.1.1 Design Requirements

A detailed design procedure is based on a design example. For this design example, use the parameters listed in [Table 2](#) as the input parameters.

Table 2. Design Example Parameters

DESIGN PARAMETER	VALUE
Input voltage V_{IN}	12 V
Output voltage V_{OUT}	5 V
REF3450-Q1 input capacitor	1 μ F
REF3450-Q1 output capacitor	10 μ F

10.2.1.2 Detailed Design Procedure

10.2.1.2.1 Input and Output Capacitors

A 1- μ F to 10- μ F electrolytic or ceramic capacitor can be connected to the input to improve transient response in applications where the supply voltage may fluctuate. Connect an additional 0.1- μ F ceramic capacitor in parallel to reduce high frequency supply noise.

A ceramic capacitor of at least a 0.1 μ F must be connected to the output to improve stability and help filter out high frequency noise. An additional 1- μ F to 10- μ F electrolytic or ceramic capacitor can be added in parallel to improve transient performance in response to sudden changes in load current; however, keep in mind that doing so increases the turnon time of the device.

Best performance and stability is attained with low-ESR, low-inductance ceramic chip-type output capacitors (X5R, X7R, or similar). If using an electrolytic capacitor on the output, place a 0.1- μ F ceramic capacitor in parallel to reduce overall ESR on the output.

10.2.1.2.2 4-Wire Kelvin Connections

Current flowing through a PCB trace produces an IR voltage drop, and with longer traces, this drop can reach several millivolts or more, introducing a considerable error into the output voltage of the reference. A 1-inch long, 5-millimeter wide trace of 1-ounce copper has a resistance of approximately 100 m Ω at room temperature; at a load current of 10 mA, this can introduce a full millivolt of error. In an ideal board layout, the reference must be mounted as close as possible to the load to minimize the length of the output traces, and, therefore, the error introduced by voltage drop. However, in applications where this is not possible or convenient, force and sense connections (sometimes referred to as Kelvin sensing connections) are provided as a means of minimizing the IR drop and improving accuracy.

Kelvin connections work by providing a set of high impedance voltage-sensing lines to the output and ground nodes. Because very little current flows through these connections, the IR drop across their traces is negligible, and the output and ground

It is always advantageous to use Kelvin connections whenever possible. However, in applications where the IR drop is negligible or an extra set of traces cannot be routed to the load, the force and sense pins for both V_{OUT} and GND can simply be tied together, and the device can be used in the same fashion as a normal 3-terminal reference (as shown in [Figure 26](#)).

10.2.1.2.3 V_{IN} Slew Rate Considerations

In applications with slow-rising input voltage signals, the reference exhibits overshoot or other transient anomalies that appear on the output. These phenomena also appear during shutdown as the internal circuitry loses power.

To avoid such conditions, ensure that the input voltage wave-form has both a rising and falling slew rate close to 6 V/ms.

10.2.1.2.4 Shutdown/Enable Feature

The REF34-Q1 references can be switched to a low power shut-down mode when a voltage of 0.5 V or lower is input to the ENABLE pin. Likewise, the reference becomes operational for ENABLE voltages of 1.6 V or higher. During shutdown, the supply current drops to less than 2 μA , useful in applications that are sensitive to power consumption.

If using the shutdown feature, ensure that the ENABLE pin voltage does not fall between 0.5 V and 1.6 V because this causes a large increase in the supply current of the device and may keep the reference from starting up correctly. If not using the shutdown feature, however, the ENABLE pin can simply be tied to the IN pin, and the reference remains operational continuously.

10.2.1.3 Application Curves

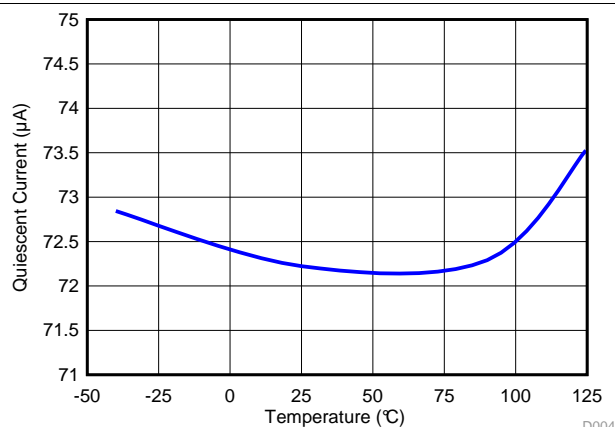


Figure 29. Quiescent Current vs Temperature

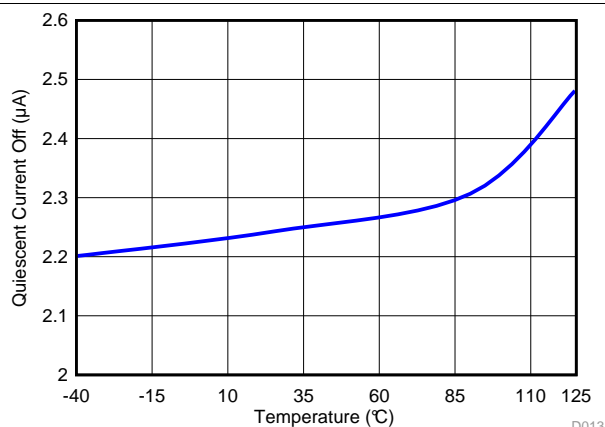


Figure 30. Quiescent Current Shutdown Mode

10.2.2 Advanced Driver Assistance Systems (ADAS) Microcontroller Connection

10.2.2.1 Basic Voltage Reference Connection

The circuit shown in [Figure 31](#) shows the basic configuration for the REF34-Q1 references.

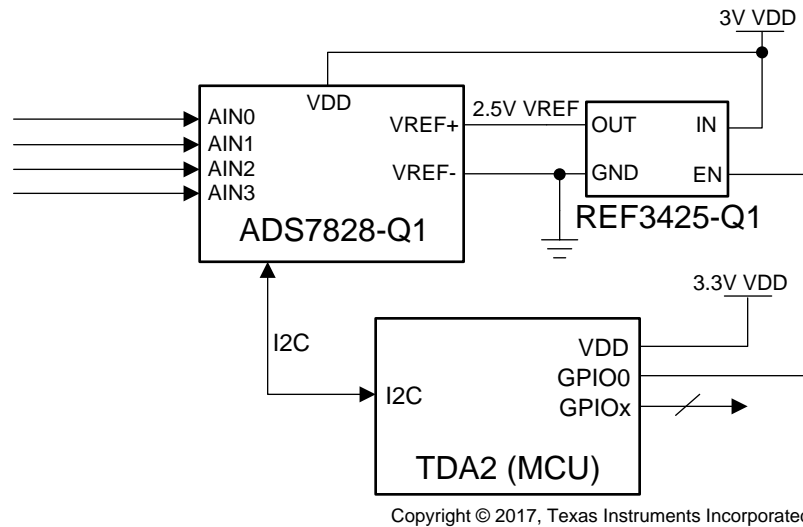


Figure 31. ADAS Microcontroller Application

10.2.2.2 Design Requirements

In ADAS applications it is common to use an ADC with a MCU to monitor the voltage rails to the MCU/DSP/FPGAs. In [Figure 31](#) the automotive TI Jacinto™ TDA2 MCU is using a ADS7828-Q1 to monitor several analog input signals and in ADAS these signals will be the system power rails. It is important to monitor these power rails because tighter rail requirements allow for further system monitoring and optimization. The REF3425-Q1 is used in this application to provide the precise voltage reference signal. In these systems it is not typical to have calibration and such the most precise low power voltage reference is necessary to be able to measure down to 1% accuracy on key power rails.

For this design example, use the parameters listed in [Table 3](#) as the input parameters and desired output parameters.

Table 3. Typical Core Voltage Rail Monitoring

Specification	Requirement
Input Voltage V_{IN}	3V
Output Voltage	2.5V
Voltage Power Rail	1V
Max Error on Voltage Power Rail	1%
Temperature Range	-40°C to 125°C

10.2.2.3 Detailed Design Procedure

It is important to keep track of the error margin in this system to make sure that the total error of the voltage reference and ADC are less than the maximum 1% error allowed. To calculate the total RSS error of a voltage reference use [Equation 5](#).

$$\text{Error}_{V_{REF}|_{\text{Total}}} = \sqrt{(\text{Accuracy})^2 + (\text{TempCo})^2 + (\text{TempHyst})^2 + (\text{Long Term Drift})^2 + (1/f \text{ Noise})^2} \quad (5)$$

With the RSS error of the voltage reference, the ADC error needs also needs to be calculated using the RSS method as seen in [Equation 6](#). [Equation 7](#) can then be used to sum both errors. It is important to make sure that only the applicable voltage reference error in relation to the measured signal is used.

$$\begin{aligned} \text{Total Unadjusted Error} &= \text{Error}_{\text{ADC}|_{\text{Total}}} \\ &= \sqrt{(\text{Gain Error})^2 + (\text{Offset Error})^2 + (\text{INL Error})^2 + (\text{DNL Error})^2} \end{aligned} \quad (6)$$

$$\text{Error}_{\text{VREF} + \text{ADC}|_{\text{Total}}} = \sqrt{(\text{Error}_{\text{VREF} @ \text{AIN}|_{\text{Total}}})^2 + (\text{Error}_{\text{ADC}|_{\text{Total}}})^2} \quad (7)$$

10.2.2.4 Enable Feature in ADAS

In ADAS applications it is important to have a low quiescent current when the automotive application does not require the ADAS system to be in use. This creates a need for a low standby power so the battery life is preserved but there is also need for the system to still be readily available to start-up with minimal delays. In such situations the MCU and other systems will go into a standby mode to ensure that the power consumption is lowered to the absolute minimum. The REF3425-Q1 offers an enable pin that can be controlled by the MCU to activate shutdown mode with causes the REF3425-Q1 to go into stand by and consume 3 μA (maximum) and allow for a longer battery life.

11 Power Supply Recommendations

The REF34-Q1 family of references feature an extremely low-dropout voltage. These references can be operated with a supply of only 50 mV above the output voltage. TI recommends a supply bypass capacitor ranging between 0.1 μ F to 10 μ F.

12 Layout

12.1 Layout Guidelines

[Figure 32](#) illustrates an example of a PCB layout for a data acquisition system using the REF34-Q1. Some key considerations are:

- Connect low-ESR, 0.1- μ F ceramic bypass capacitors at V_{IN} , V_{REF} of the REF34-Q1.
- Decouple other active devices in the system per the device specifications.
- Using a solid ground plane helps distribute heat and reduces electromagnetic interference (EMI) noise pickup.
- Place the external components as close to the device as possible. This configuration prevents parasitic errors (such as the Seebeck effect) from occurring.
- Do not run sensitive analog traces in parallel with digital traces. Avoid crossing digital and analog traces if possible, and only make perpendicular crossings when absolutely necessary.

12.2 Layout Example

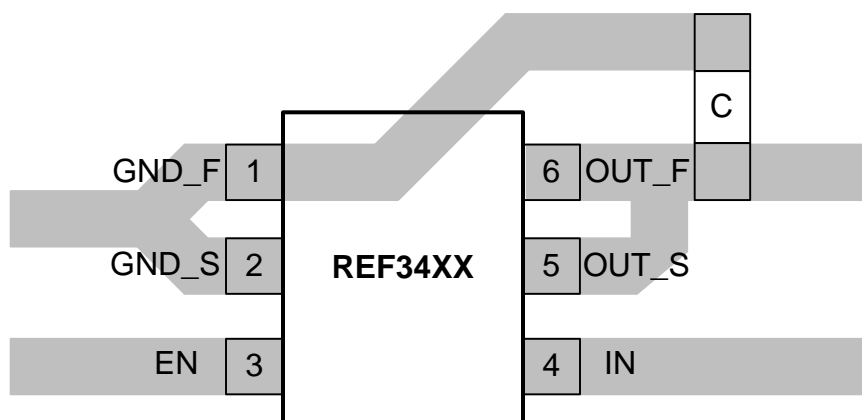


Figure 32. Layout Example

13 Device and Documentation Support

13.1 Documentation Support

13.1.1 Related Documentation

For related documentation see the following:

- [INA21x Voltage Output, Low- or High-Side Measurement, Bidirectional, Zero-Drift Series, Current-Shunt Monitors](#)
- [Low-Drift Bidirectional Single-Supply Low-Side Current Sensing Reference Design](#)

13.1.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to order now.

Table 4. Related Links

PARTS	PRODUCT FOLDER	ORDER NOW	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
REF3425-Q1	Click here	Click here	Click here	Click here	Click here
REF3430-Q1	Click here	Click here	Click here	Click here	Click here
REF3433-Q1	Click here	Click here	Click here	Click here	Click here
REF3440-Q1	Click here	Click here	Click here	Click here	Click here
REF3450-Q1	Click here	Click here	Click here	Click here	Click here

13.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

13.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

13.4 Trademarks

Jacinto, E2E are trademarks of Texas Instruments.
All other trademarks are the property of their respective owners.

13.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

13.6 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
REF3425QDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	1OLC	Samples
REF3430QDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	1OMC	Samples
REF3433QDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	1ONC	Samples
REF3440QDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	1OOC	Samples
REF3450QDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	1OPC	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
REF3425QDBVRQ1	SOT-23	DBV	6	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
REF3430QDBVRQ1	SOT-23	DBV	6	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
REF3433QDBVRQ1	SOT-23	DBV	6	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
REF3440QDBVRQ1	SOT-23	DBV	6	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
REF3450QDBVRQ1	SOT-23	DBV	6	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

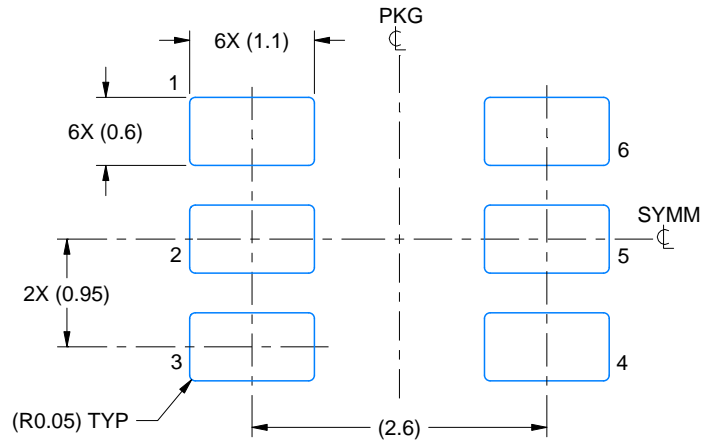
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
REF3425QDBVRQ1	SOT-23	DBV	6	3000	213.0	191.0	35.0
REF3430QDBVRQ1	SOT-23	DBV	6	3000	213.0	191.0	35.0
REF3433QDBVRQ1	SOT-23	DBV	6	3000	213.0	191.0	35.0
REF3440QDBVRQ1	SOT-23	DBV	6	3000	213.0	191.0	35.0
REF3450QDBVRQ1	SOT-23	DBV	6	3000	213.0	191.0	35.0

EXAMPLE BOARD LAYOUT

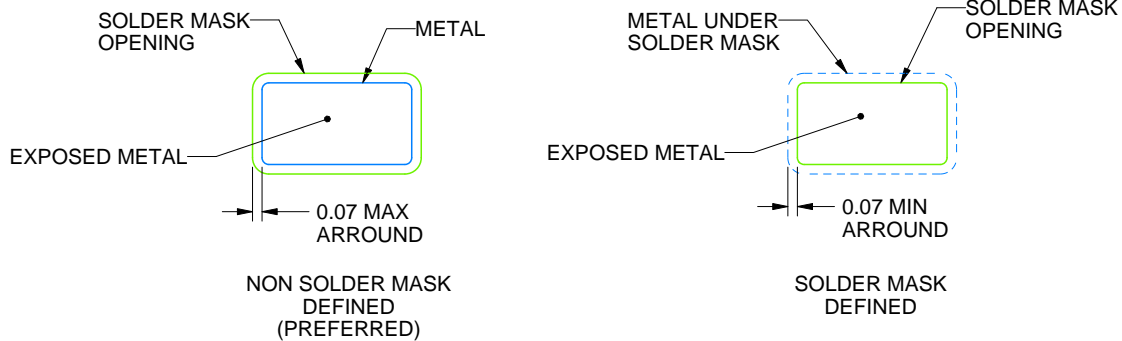
DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214840/B 03/2018

NOTES: (continued)

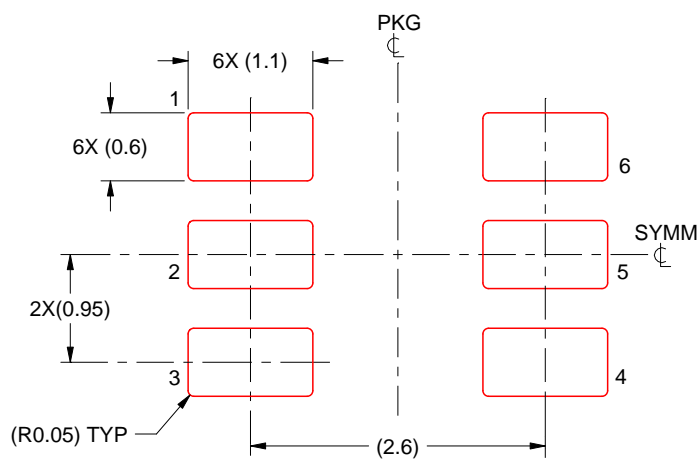
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214840/B 03/2018

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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